# POLISHING CLOTH AND METHOD OF PRODUCING SAME

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### Background of the Invention

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This invention relates to a polishing cloth and more particularly to a polishing cloth suited to the final polishing of hard disk substrates and silicon wafers as well as a method of its production.

It has been known to use a polishing cloth of the type produced by removing the non-foamed layer (referred to as the skin layer) which constitutes a surface portion of the foamed layer by buffing or by means of a knife so as to expose air bubble cells generated inside the foamed layer on the surface by  $1-1000\mu m$ . This was both because it is necessary to hold the polishing liquid in the air bubble cells and because the surface of a foamed resin material normally produced is not sufficiently smooth and flat. Surface roughness due to air bubble cells affects the surface flatness adversely, and it is becoming a serious problem because surface roughness results on surfaces polished by such a polishing cloth. The problem of surface roughness is recently becoming particularly important in the technical field of final polishing of hard disk substrates and silicon wafers and it is becoming essential to reduce such surface roughness.

In view of the problem of reducing surface roughness, Japanese Patent 3,187,769 disclosed the technology of using sandpaper or the like with fine particles to buff the surface of a polishing cloth after air bubbles are exposed, and Japanese Patent Publication Tokkai 2001-62704 disclosed the technology of minutely buffing the skin layer without exposing air bubbles on the surface to improve surface flatness. The former technology is not satisfactory because the surface flatness cannot be improved over a certain limit because air bubbles are exposed on the polishing surface. Neither is the latter technology satisfactory but it is because the polishing liquid cannot be retained.

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### Summary of the Invention

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It is therefore an object of this invention, in view of the failure of the prior art technologies to properly address the aforementioned problem, to provide a polishing cloth with an improved surface flatness, capable of retaining a polishing liquid.

It is another object of this invention to provide a method of producing such a cloth without increasing the production cost and without requiring any additional production equipment.

A polishing cloth embodying this invention may be characterized as comprising a base material and a surface layer stacked over the base material, the surface layer comprising a foamed layer and a non-foamed layer, the foamed layer including air bubble cells and the non-foamed layer having an externally exposed surface where linear cuts are formed so as to reach the air bubble cells such that the air bubble cells communicate with the exterior through the linear cuts. These linear cuts are controlled to be  $10\mu$ m or less in length. The base material may comprise any one selected from resin materials such as polyethylene terephthalate, vinyl polychloride and cellophane, rubber materials, paper materials, cloth materials such as a woven cloth and an unwoven cloth, metal materials and foamed materials. The surface layer comprises foamed polyurethane resin and may have unevenness produced by a gravure process or an embossing work process.

A method embodying this invention for producing such a polishing cloth may be characterized as comprising the steps of applying a foamable coating material comprising a foamable resin over a surface of the base material, foaming the foamable coating material to thereby form the surface layer, and forming the linear cuts through the non-foamed layer. These linear cuts are formed by a buffing process so as to be  $10\mu m$  or less in length.

If a polishing cloth embodying this invention is used, not only can waviness, or surface roughness, of a polished product be significantly improved but damages due to the polishing process can also be reduced. Such polishing cloths can be produced by a method embodying this invention at a reduced production cost at an improved throughput without requiring any additional equipment or space for such a new equipment.

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## Brief Description of the Drawings

Fig. 1 is a schematic sectional view of an example of polishing cloth embodying this invention.

Figs 2A-1 and 2A-2 are enlarged photographs respectively of a sectional view and a plan view of a polishing cloth embodying this invention and Figs 2B-1 and 2B-2 are enlarged photographs respectively of a sectional view and a plan view of a prior art polishing cloth.

Fig. 3 is a graph which shows the roughness of polished surfaces polished by a polishing cloth embodying this invention and a prior art polishing cloth.

## Detailed Description of the Invention

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The invention is described next in detail with reference to the drawings. Fig. 1 shows a polishing cloth 1 embodying this invention, comprising a base layer 2 and a surface layer 7 which is stacked on the surface of the base layer 2. The base layer 2 is made of any of resin materials such as polyethylene terephthalate (PET), vinyl chloride and cellophane, rubber, paper, a cloth material such as a woven cloth or a non-woven cloth, a metallic material or a foamed material. The surface layer 7 is made of foamed polyurethane resin and includes both a foamed layer 3 and a skin layer 4. The foamed layer 3 contains a large number of air bubble cells 5 inside. The skin layer 4 is formed when foaming urethane resin is foamed and its surface is extremely flat and smooth. Linear cuts 6, which characterize this invention, are formed on the surface of the skin layer 4. Linear cuts 6 are essentially elongated grooves. The depth of these linear cuts 6 is such that they completely penetrate the skin layer 4. Their lengths are preferably controlled to be  $10\mu m$  or less. Some of the linear cuts 6 which completely penetrate the skin layer 4 reach and open to an air bubble cell 5. These linear cuts 6 serve to retain a polishing liquid and to take in debris and impurities during a polishing operation. The linear cuts 6 also serve to allow the gas remaining within the air bubble cells 5 to escape and to be discharged therethrough to the exterior. The shape, length and depth of the linear cuts 6 may be selected according to the characteristics of the polishing liquid to be used such as the diameter of the abrading particles contained therein or its viscosity. The linear cuts 6 may be formed either continuously or intermittently.

As a variation, the surface of the skin layer 4 may be made uneven by gravure or embossing finish process. This may serve to reduce the frictional resistance.

Figs. 2A-1, 2A-2, 2B-1 and 2B-2 are microscopic photographs of a polishing cloth embodying this invention and a prior art polishing cloth for comparing their sectional views and their surfaces, Figs. 2A-1 and 2A-2 showing sectional and plan views of a polishing cloth of this invention and Figs. 2B-1 and 2B-2 showing sectional and plan views of a prior art polishing cloth produced by forming a foamed layer on a base and then buffing the surface so as to expose air bubbles. A comparison between Figs. 2A-1 and 2B-1 shows that a skin layer is formed at the top of the polishing cloth of this invention but that there is no skin layer on the prior art polishing cloth. A comparison between Figs. 2A-2 and 2B-2 shows that the surface of the polishing cloth embodying this invention is very flat and smooth, having hardly any protrusions or indentations but that the surface of the prior art polishing cloth has air bubbles exposed and is significantly bumpy.

A method of producing the polishing cloth 1 of this invention includes the step of applying a foaming paint (or coating material) comprising a foaming resin on the surface of a base material. The foaming paint to be used according to this invention may preferably comprise foaming polyurethane resin (or polyurethane foam). This foaming polyurethane resin may preferably be formed by dissolving a mixture of organic diisocyanate, polyoles and a chain-elongating agent in a solvent and, if necessary, adding an additive such as a foaming agent and a foam improving agent. Examples of organic diisocyanate include diphenylmethane-4,4'-diisocyante and toolylene-2. Examples of polyole include polyester polyoles such as polyethylene adipate glycol, polypropylene adipate glycol and polyethylenepropylene adipate glycol, and polyether polyoles such as polyethylene ether glycol. Examples of chain-elongating agent include glycols such as ethylene glycol and propylene glycol, diamines such as ethylene diamine and trimethylene diamine, and amino-alcohol. Examples of solvent include water-miscible dimethyl formaldehyde, dimethyl sulfoxide, tetrahydro furan, dimethyl acetoamide, ethyl acetate and dioxane. Examples of compounding agent include water, fleon, silicone oil, vinyl polychloride, polyamides and polyacrylonitril. The foamable polyurethane resin may be coated by using an appropriate coating means such as a roll coater.

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The method for producing a polishing cloth of this invention also includes the step of foaming the foamable coating material to form the surface layer. The foaming may be effected by a wet method or a dry method. If a wet method is used, the step of submerging in water for coagulation and thereafter washing and drying to remove the solvent is included.

The production method of this invention further includes the step of forming linear cuts on the surface of the skin layer. The linear cuts are formed by a buffing process but a different process may be employed for the purpose. The length of the linear cuts is controlled to be  $10\mu m$  or less. If an unwoven cloth is used as the base material, it is preferable to form the linear cuts after the surface of the foamable polyurethane resin is subjected to a thermal process, a press working process or a fine buffing process since the surface of the skin layer is not sufficiently flat and smooth.

Since the production method of this invention is an improvement over the prior art method for producing a prior art polishing cloth having externally exposed air bubble cells, a prior art production equipment may be employed without modifications. Thus, the number of production steps does not increase over the prior art method of production and there is no need for any extra equipment. In other words, there is no problem of an increase in the production cost or an additional space for equipment.

A comparison test was carried out between the polishing cloth of this invention and the prior art polishing cloth referenced with respect to Figs. 2A-1, 2A-2, 2B-1 and 2B-2. A polishing liquid containing colloidal silica with average diameter of about 80nm by about 5% (produced by Nihon Microcoating Co., Ltd) was used. Samples to be used for the polishing were prepared by polishing 3.5-inch aluminum substrates subjected to electroless NiP plating with a polishing pad (Politex DG pad produced by Rodel Co., Ltd.) by using a diluted liquid prepared by diluting a polishing liquid (DISKLITE3471 produced by Fujimi Incorporated) with pure water at the rate of 1:3. At this point of time, that is, before the test polishing, the surface roughness was 6-8Å.

Table 1 shows other test conditions.

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Table 1

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Polishing machine	Double-side polisher HAMAI-9BF (produced by Hamai Sangyo Kabushiki Kaisha)
Applied pressure	90g/cm <sup>2</sup>
Rotation of lapping plates	40rpm
Supply of polishing liquid	0.2 liter/minute
Polishing time	4 minutes
Stock removal	About 1µm from both sides

For measurements and evaluations, use was made of a scan-type white-color interferometer (New View 5000 produced by Zygo, Inc. with objective lens 10x and intermediate lens 0.8x and measurements taken within the wavelength range of 0.05-2mm by filtering off wavelengths less than 0.05mm and greater than 2.0mm) to measure the average roughness Wa (in Å) as waviness.

Fig. 3 shows the measured waviness as the average from ten batches. The graph shows that the average Wa as waviness is 2.44Å if a conventional polishing cloth is used but is only 1.41Å if a polishing cloth of this invention is used. This represents an improvement by about 40% in the waviness. It has also been found that there was also a decrease in damage due to coagulated polishing agent and debris if a polishing cloth of this invention is used. It may be believed that this was because the linear cuts formed in the skin layer retain the polishing liquid to an appropriate degree while taking in debris of polishing.